

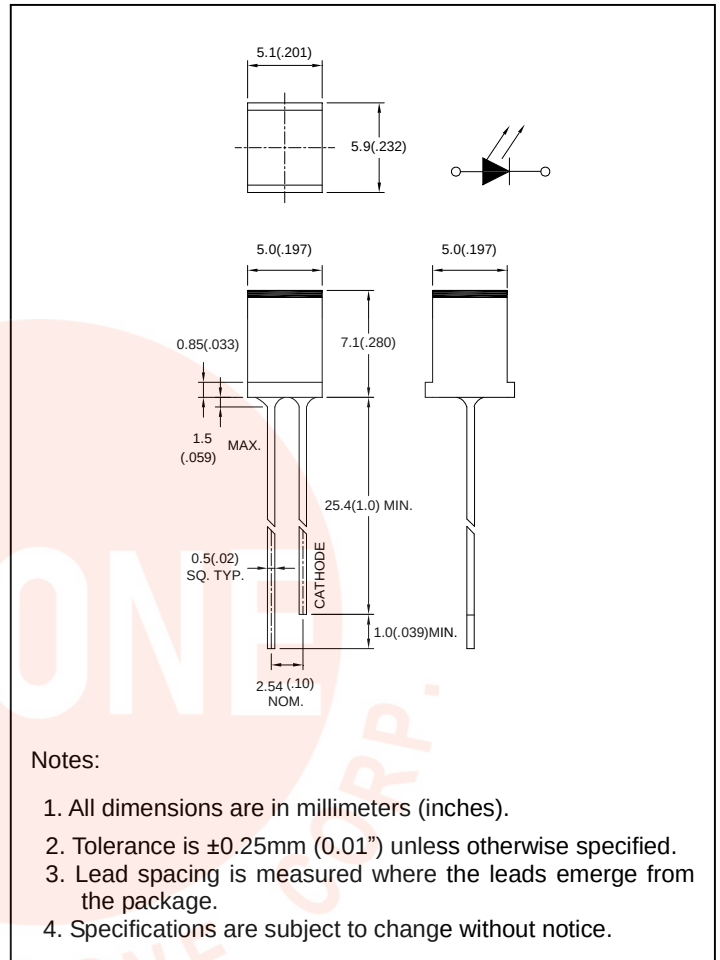
### ● Features:

1. Chip material: GaAsP/GaP
2. Emitted color : Hi-Eff Red
3. Lens Appearance : Red Diffused
4. Low power consumption.
5. Most suitable for use like level indicator.
6. Excellent uniformity of light emittance.
7. Long life solid state reliability.
8. Compatible.
9. This product don't contained restriction substance, compliance RoHS standard.

### ● Applications:

1. TV set
2. Monitor
3. Telephone
4. Computer
5. Circuit board

### ● Package dimensions:



### ● Absolute maximum ratings( $T_a=25^\circ\text{C}$ )

| Parameter             | Symbol    | Rating                                    | Unit |
|-----------------------|-----------|-------------------------------------------|------|
| Power Dissipation     | $P_d$     | 80                                        | mW   |
| Forward Current       | $I_F$     | 30                                        | mA   |
| Peak Forward Current  | $I_{FP}$  | 150                                       | mA   |
| Reverse Voltage       | $V_R$     | 5                                         | V    |
| Operating Temperature | $T_{opr}$ | $-40^\circ\text{C} \sim 85^\circ\text{C}$ |      |
| Storage Temperature   | $T_{stg}$ | $-40^\circ\text{C} \sim 85^\circ\text{C}$ |      |

\*<sup>1</sup>Condition for  $I_{FP}$  is pulse of 1/10 duty and 0.1msec width.

● **Electrical and optical characteristics(Ta=25°C)**

| Parameter                | Symbol            | Condition            | Min. | Typ. | Max. | Unit |
|--------------------------|-------------------|----------------------|------|------|------|------|
| Forward Voltage          | V <sub>F</sub>    | I <sub>F</sub> =20mA | -    | 2.0  | 2.6  | V    |
| Luminous Intensity       | I <sub>v</sub>    | I <sub>F</sub> =20mA | -    | 10   | -    | mcd  |
| Reverse Current          | I <sub>R</sub>    | V <sub>R</sub> =5V   | -    | -    | 100  | μA   |
| Peak Wave Length         | λ <sub>p</sub>    | I <sub>F</sub> =20mA | -    | 640  | -    | nm   |
| Dominant Wave Length     | λ <sub>d</sub>    | I <sub>F</sub> =20mA | 617  | -    | 638  | nm   |
| Spectral Line Half-width | Δλ                | I <sub>F</sub> =20mA | -    | 35   | -    | nm   |
| Viewing Angle            | 2θ <sub>1/2</sub> | I <sub>F</sub> =20mA | -    | 150  | -    | deg  |

● **Typical Electro-Optical Characteristics Curves**

Fig.1 Relative intensity vs. Wavelength

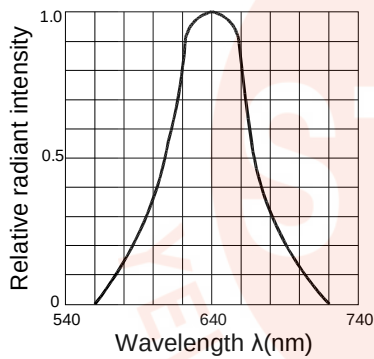


Fig.2 Forward current derating curve vs. Ambient temperature

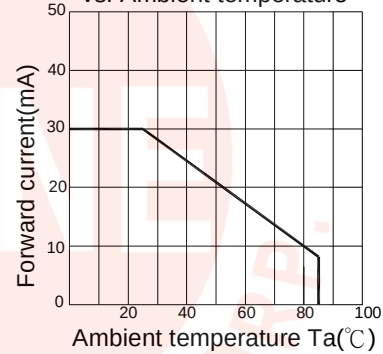


Fig.3 Forward current vs. Forward voltage

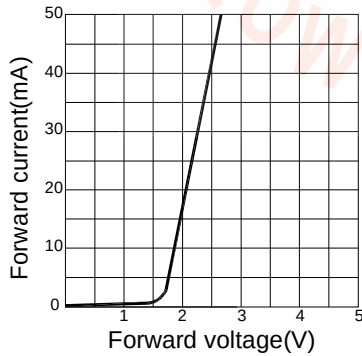


Fig.4 Relative luminous intensity vs. Ambient temperature

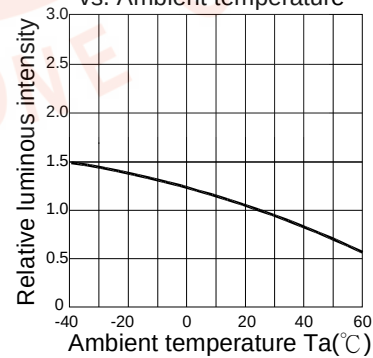


Fig.5 Relative luminous intensity vs. Forward current

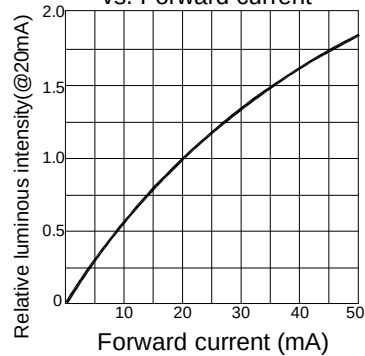
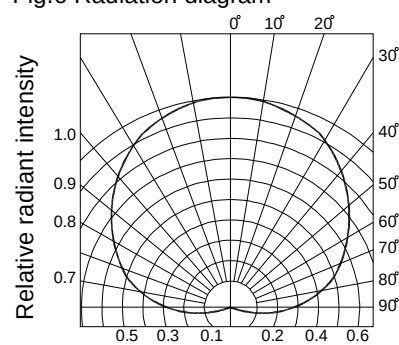


Fig.6 Radiation diagram





● Bin Limits

1. Intensity Bin Limits (At  $I_F = 20\text{mA}$ )

| Bin Code | Min. (mcd) | Max. (mcd) |
|----------|------------|------------|
| G        | 3.7        | 5.5        |
| H        | 5.5        | 8.2        |
| J        | 8.2        | 12.3       |
| K        | 12.3       | 18.5       |
| L        | 18.5       | 28         |

● Bin : x



NOTES: 1. Tolerance of measurement of luminous intensity.

:  $\pm 15\%$

● Reliability Test

| Classification     | Test Item                              | Reference Standard                                                            | Test Conditions                                                                                          | Result |
|--------------------|----------------------------------------|-------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|--------|
| Endurance Test     | Operation Life                         | MIL-STD-750:1026<br>MIL-STD-883:1005<br>JIS-C-7021 :B-1                       | I <sub>F</sub> =20mA<br>Ta=+25°C±5°C<br>Test time=1,000hrs                                               | 0/32   |
|                    | High Temperature High Humidity Storage | MIL-STD-202:103B<br>JIS-C-7021 :B-11                                          | Ta=+85°C±5°C<br>RH=90%-95%<br>Test time=240hrs                                                           | 0/32   |
|                    | High Temperature Storage               | MIL-STD-883:1008<br>JIS-C-7021 :B-10                                          | High Ta=+85°C±5°C<br>Test time=1,000hrs                                                                  | 0/32   |
|                    | Low Temperature Storage                | JIS-C-7021 :B-12                                                              | Low Ta=-45°C±5°C<br>Test time=1,000hrs                                                                   | 0/32   |
| Environmental Test | Temperature Cycling                    | MIL-STD-202:107D<br>MIL-STD-750:1051<br>MIL-STD-883:1010<br>JIS-C-7021 :A-4   | Ta: +85°C (30min) ~ +25°C (5min) ~<br>-45°C (30min) ~ +25°C (5min)<br>Test Time : 70min/ctcle 10cycle    | 0/32   |
|                    | Thermal Shock                          | MIL-STD-202:107D<br>MIL-STD-750:1051<br>MIL-STD-883:1011                      | -45°C±5°C ~+85°C±5°C<br>20min 20min<br>Test Time=10cycle                                                 | 0/32   |
|                    | Solder Resistance                      | MIL-STD-202:201A<br>MIL-STD-750:2031<br>JIS-C-7021 :A-1                       | Preheating :<br>120°C, within 120-180 sec.<br>Operation heating :<br>255°C±5°C within 5 sec. 260°C (Max) | 0/32   |
|                    | Solderability                          | MIL-STD-202F:208D<br>MIL-STD-750D:2026<br>MIL-STD-883D:2003<br>JIS C 7021:A-2 | T.sol=230±5°C<br>Dwell Time=5±1secs                                                                      | 0/32   |

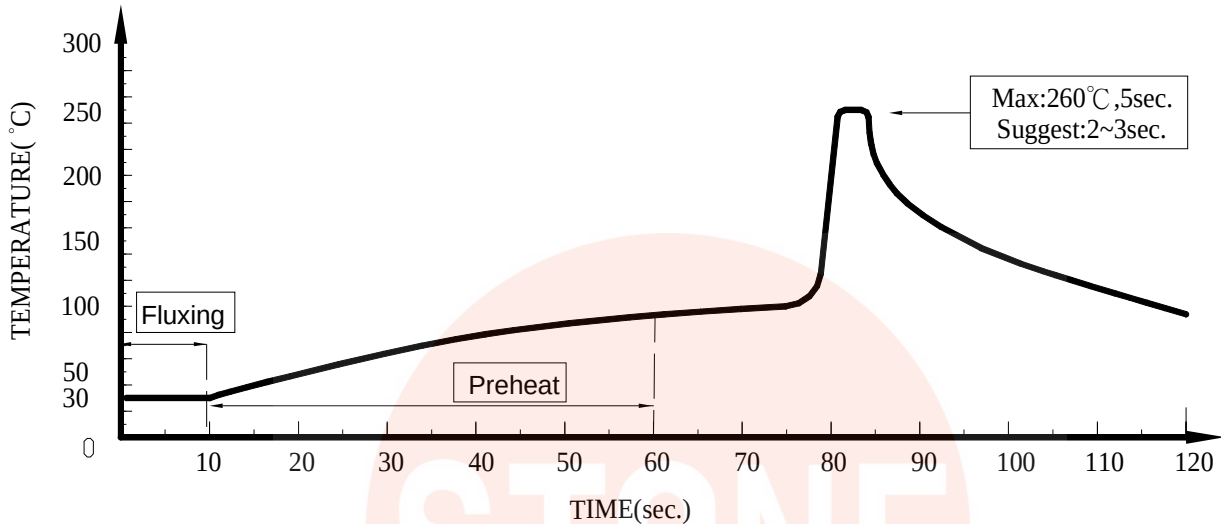
● Judgment criteria of failure for the reliability

| Measuring items    | Symbol                | Measuring conditions | Judgment criteria for failure |
|--------------------|-----------------------|----------------------|-------------------------------|
| Forward voltage    | V <sub>F</sub> (V)    | I <sub>F</sub> =20mA | Over U <sup>1</sup> x1.2      |
| Reverse current    | I <sub>R</sub> (uA)   | V <sub>R</sub> =5V   | Over U <sup>1</sup> x2        |
| Luminous intensity | I <sub>v</sub> ( mcd) | I <sub>F</sub> =20mA | Below S <sup>1</sup> X0.5     |

Note: 1. U means the upper limit of specified characteristics. S means initial value.

2. Measurement shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.

## ●Dip Soldering



1. Please avoid any external stress applied to the lead-frames and epoxy while the LEDs are at high temperature, especially during soldering
2. DIP soldering and hand soldering should not be done more than one time.
3. After soldering, avoid the epoxy lens from mechanical shock or vibration until the LEDs are back to room temperature.
4. Avoid rapid cooling during temperature ramp-down process
5. Although the soldering condition is recommended above,  
soldering at the lowest possible temperature is feasible for the LEDs

## ●IRON Soldering

A : Max : 350°C Within 3 sec. One time only.

B : The products of 3mm without flange, welding condition of flat plate PCB Max : 350°C  
Within 2 sec. One time only

